Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	38	(p?n junction) and (capacti\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	ADJ	ON	2008/01/10 10:14
L3	36211	(p?n junction)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	ADJ	ON	2008/01/10 10:14
L4	57	(field shaping region)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	ADJ	ON	2008/01/10 10:17
L5	. 9	(ep-519741-\$ ep-1291926-\$ ep-823736-\$ wo-2003043089-\$).did. "20030006458". PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2008/01/10 10:17
L6	142	((hueting) near2 (raymond)).INV. ((ANCO) near2 (HERINGA)).INV. ((jan) near2 (slotboom)).INV.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2008/01/10 10:17
L7	4283	(257/168 257/409 257/107 438/133 438/197).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2008/01/10 10:15
L8	4339	Ta2O5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2008/01/10 10:17

L9	21292	Ta2O5 or "tantalum oxide"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	OR	ОИ	2008/01/10 10:17
L10	2	4 9	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:23
LII	370	3 9	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:25
L12	3	("first and second" or "upper and lower") adj electrode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:26
L13	0	3 12	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:25
L14	126335	((first and second) or (upper and lower)) adj electrode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:26
L15	2707	3 14	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:26

L16	41539	((upper and lower)) adj electrode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:27
L17	698	3 16	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:27
L18	96	(((upper and lower)) adj electrode) same 3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:43
L19	386559	sidewall	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:43
L20	4	18 19	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:46
L21	0	(interlayer adj insulator) and 18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:46
L22	3	(interlayer adj insulat\$3) and 18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 10:49

L23	10	(gate adj oxide) and 18	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 11:34
L24	2	"20020030237".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 14:00
L25	2	"20010048131".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 15:31
L26	1	24 and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	AND	ON	2008/01/10 15:34